

1.本站收集的数据手册和产品资料都来自互联网,版权归原作者所有。如读者和版权方有任 何异议请及时告之,我们将妥善解决。

本站提供的中文数据手册是英文数据手册的中文翻译,其目的是协助用户阅读,该译文无法自动跟随原稿更新,同时也可能存在翻译上的不当。建议读者以英文原稿为参考以便获得更精准的信息。

3.本站提供的产品资料,来自厂商的技术支持或者使用者的心得体会等,其内容可能存在描 叙上的差异,建议读者做出适当判断。

4.如需与我们联系,请发邮件到marketing@iczoom.com,主题请标有"数据手册"字样。

## **Read Statement**

1. The datasheets and other product information on the site are all from network reference or other public materials, and the copyright belongs to the original author and original published source. If readers and copyright owners have any objections, please contact us and we will deal with it in a timely manner.

2. The Chinese datasheets provided on the website is a Chinese translation of the English datasheets. Its purpose is for reader's learning exchange only and do not involve commercial purposes. The translation cannot be automatically updated with the original manuscript, and there may also be improper translations. Readers are advised to use the English manuscript as a reference for more accurate information.

3. All product information provided on the website refer to solutions from manufacturers' technical support or users the contents may have differences in description, and readers are advised to take the original article as the standard.

4. If you have any questions, please contact us at marketing@iczoom.com and mark the subject with "Datasheets".

# 

#### LOW SKEW 1 TO 4 CLOCK BUFFER

#### DATASHEET

#### ICS553

#### Description

The ICS553 is a low skew, single input to four output, clock buffer. Part of IDT's ClockBlocks<sup>TM</sup> family, this is our lowest skew, small clock buffer.

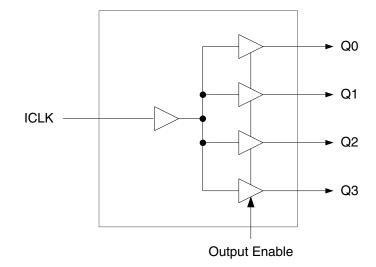
See the ICS552-02 for a 1 to 8 low skew buffer. For more than eight outputs, see the MK74CBxxx Buffalo<sup>TM</sup> series of clock drivers.

IDT makes many non-PLL and PLL based low skew output devices as well as Zero Delay Buffers to synchronize clocks. Contact us for all of your clocking needs.

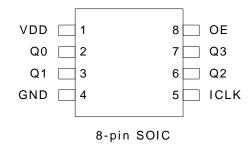
#### Features

- Extremely low skew outputs (50 ps maximum)
- Packaged in 8-pin SOIC
- Pb (lead) free package
- Low power CMOS technology
- Operating voltages of 2.5 V to 5 V
- Output Enable pin tri-states outputs
- 5 V tolerant input clock
- Commercial (0 to +70°C) and Industrial (-40 to +85°C) temperature ranges available

#### **Block Diagram**



#### **Pin Assignment**



#### **Pin Descriptions**

Pin Number	Pin Name	Pin Type	Pin Description
1	VDD	Power	Connect to +2.5 V, +3.3 V or +5.0 V.
2	Q0	Output	Clock output 0.
3	Q1	Output	Clock output 1.
4	GND	Power	Connect to ground.
5	ICLK	Input	Clock input, 5 V tolerant input.
6	Q2	Output	Clock Output 2.
7	Q3	Output	Clock Output 3.
8	OE	Input	Output Enable. Tri-states outputs when low. Connect to VDD for normal operation.

#### **External Components**

A minimum number of external components are required for proper operation. A decoupling capacitor of 0.01  $\mu$ F should be connected between VDD on pin 1 and GND on pin 4, as close to the device as possible. A 33  $\Omega$  series terminating resistor may be used on each clock output if the trace is longer than 1 inch.

To achieve the low output skew that the ICS553 is capable of, careful attention must be paid to board layout. Essentially, all four outputs must have identical terminations, identical loads and identical trace geometries. If they do not, the output skew will be degraded. For example, using a  $30\Omega$  series termination on one output (with  $33\Omega$  on the others) will cause at least 15 ps of skew.

#### **Absolute Maximum Ratings**

Stresses above the ratings listed below can cause permanent damage to the ICS553. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

Item	Rating
Supply Voltage, VDD	7 V
Output Enable and All Outputs	-0.5 V to VDD+0.5 V
ICLK	-0.5 V to 5.5 V
Ambient Operating Temperature (commercial)	0 to +70° C
Ambient Operating Temperature (industrial)	-40 to +85° C
Storage Temperature	-65 to +150° C
Junction Temperature	125°C
Soldering Temperature	260° C

#### **Recommended Operation Conditions**

Parameter	Min.	Тур.	Max.	Units
Ambient Operating Temperature (commercial)	0		+70	°C
Ambient Operating Temperature (industrial)	-40		+85	°C
Power Supply Voltage (measured in respect to GND)	+2.375		+5.25	V

#### **DC Electrical Characteristics**

VDD=2.5 V ±5%, Ambient temperature -40 to +85° C, unless stated otherwise

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Operating Voltage	VDD		2.375		2.625	V
Input High Voltage, ICLK	V <sub>IH</sub>	Note 1	VDD/2+0.5		5.5	V
Input Low Voltage, ICLK	V <sub>IL</sub>	Note 1			VDD/2-0.5	V
Input High Voltage, OE	V <sub>IH</sub>		1.8		VDD	V
Input Low Voltage, OE	V <sub>IL</sub>				0.7	V
Output High Voltage	V <sub>OH</sub>	I <sub>OH</sub> = -16 mA	2			V
Output Low Voltage	V <sub>OL</sub>	I <sub>OL</sub> = 16 mA			0.4	V
Operating Supply Current	IDD	No load, 135 MHz		25		mA
Nominal Output Impedance	ZO			20		Ω
Input Capacitance	C <sub>IN</sub>	ICLK, OE pin		5		pF
Short Circuit Current	I <sub>OS</sub>			±28		mA

#### **DC Electrical Characteristics (continued)**

VDD=3.3 V ±5% , Ambient temperature -40 to +85° C, unless stated otherwise

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Operating Voltage	VDD		3.15		3.45	V
Input High Voltage, ICLK	V <sub>IH</sub>	Note 1	VDD/2+0.7		5.5	V
Input Low Voltage, ICLK	V <sub>IL</sub>	Note 1			VDD/2-0.7	V
Input High Voltage, OE	V <sub>IH</sub>		2		VDD	V
Input Low Voltage, OE	V <sub>IL</sub>				0.8	V
Output High Voltage	V <sub>OH</sub>	I <sub>OH</sub> = -25 mA	2.4			V
Output Low Voltage	V <sub>OL</sub>	I <sub>OL</sub> = 25 mA			0.4	V
Output High Voltage (CMOS Level)	V <sub>OH</sub>	I <sub>OH</sub> = -12 mA	VDD-0.4			V
Operating Supply Current	IDD	No load, 135 MHz		35		mA
Nominal Output Impedance	Z <sub>O</sub>			20		Ω
Input Capacitance	C <sub>IN</sub>	ICLK, OE pin		5		pF
Short Circuit Current	I <sub>OS</sub>			±50		mA

#### VDD=5 V $\pm$ 5% , Ambient temperature -40 to +85° C, unless stated otherwise

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Operating Voltage	VDD		4.75		5.25	V
Input High Voltage, ICLK	V <sub>IH</sub>	Note 1	VDD/2+1		5.5	V
Input Low Voltage, ICLK	V <sub>IL</sub>	Note 1			VDD/2-1	V
Input High Voltage, OE	V <sub>IH</sub>		2		VDD	V
Input Low Voltage, OE	V <sub>IL</sub>				0.8	V
Output High Voltage	V <sub>OH</sub>	I <sub>OH</sub> = -35 mA	2.4			V
Output Low Voltage	V <sub>OL</sub>	I <sub>OL</sub> = 35 mA			0.4	V
Output High Voltage (CMOS Level)	V <sub>OH</sub>	I <sub>OH</sub> = -12 mA	VDD-0.4			V
Operating Supply Current	IDD	No load, 135 MHz		45		mA
Nominal Output Impedance	Z <sub>O</sub>			20		Ω
Input Capacitance	C <sub>IN</sub>	ICLK, OE pin		5		pF
Short Circuit Current	I <sub>OS</sub>			±80		mA

Notes: 1. Nominal switching threshold is VDD/2

#### **AC Electrical Characteristics**

VDD = 2.5 V ±5%, Ambient Temperature -40	to +85° C, unless stated otherwise
--	------------------------------------

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Input Frequency			0		200	MHz
Output Rise Time	t <sub>OR</sub>	0.8 to 2.0 V, C <sub>L</sub> =15 pF		1.0	1.5	ns
Output Fall Time	t <sub>OF</sub>	2.0 to 0.8 V, C <sub>L</sub> =15 pF		1.0	1.5	ns
Propagation Delay	Note 1		2.2	3	5	ns
Additive Period Jitter					1	ps
Output to Output Skew	Note 2	Rising edges at VDD/2		0	50	ps
Device to Device Skew		Rising edges at VDD/2			500	ps

#### VDD = 3.3 V ±5%, Ambient Temperature -40 to +85°C, unless stated otherwise

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Input Frequency			0		200	MHz
Output Rise Time	t <sub>OR</sub>	0.8 to 2.0 V, C <sub>L</sub> =15 pF		0.6	1.0	ns
Output Fall Time	t <sub>OF</sub>	2.0 to 0.8 V, C <sub>L</sub> =15 pF		0.6	1.0	ns
Propagation Delay	Note 1		2.0	2.4	4	ns
Additive Period Jitter					1	ps
Output to Output Skew	Note 2	Rising edges at VDD/2		0	50	ps
Device to Device Skew		Rising edges at VDD/2			500	ps

#### VDD = 5 V ±5%, Ambient Temperature -40 to +85° C, unless stated otherwise

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Input Frequency			0		200	MHz
Output Rise Time	t <sub>OR</sub>	0.8 to 2.0 V, C <sub>L</sub> =15 pF		0.3	0.7	ns
Output Fall Time	t <sub>OF</sub>	2.0 to 0.8 V, C <sub>L</sub> =15 pF		0.3	0.7	ns
Propagation Delay	Note 1		1.8	2.5	4	ns
Additive Period Jitter					1	ps
Output to Output Skew	Note 2	Rising edges at VDD/2		0	50	ps
Device to Device Skew		Rising edges at VDD/2			500	ps

Notes: 1. With rail to rail input clock

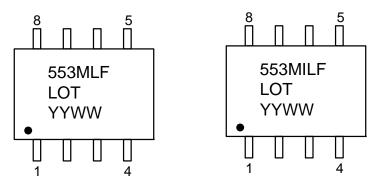
2. Between any 2 outputs with equal loading.

3. Duty cycle on outputs will match incoming clock duty cycle. Consult IDT for tight duty cycle clock generators.

#### **Thermal Characteristics**

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Thermal Resistance Junction to	$\theta_{JA}$	Still air		150		° C/W
Ambient	$\theta_{JA}$	1 m/s air flow		140		° C/W
	$\theta_{JA}$	3 m/s air flow		120		° C/W
Thermal Resistance Junction to Case	θ <sub>JC</sub>			40		° C/W

#### **Marking Diagrams**

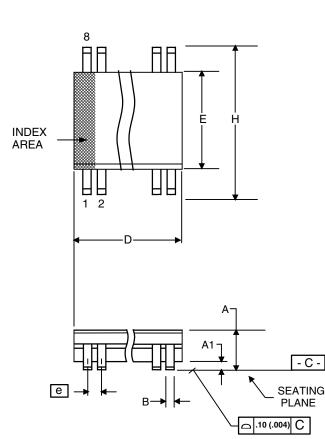


Notes:

- 1. "LOT" is the lot number.
- 2. YYWW is the last two digits of the year and week that the part was assembled.
- 3 "LF" denotes RoHS compliant package.
- 4. "I" denotes industrial temperature range device.
- 5. Bottom marking: country of origin.

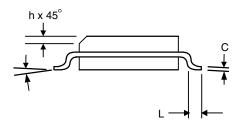
#### Package Outline and Package Dimensions (8-pin SOIC, 150 Mil. Narrow Body)

Package dimensions are kept current with JEDEC Publication No. 95



	Millin	Millimeters		nes*
Symbol	Min	Max	Min	Мах
А	1.35	1.75	.0532	.0688
A1	0.10	0.25	.0040	.0098
В	0.33	0.51	.013	.020
С	0.19	0.25	.0075	.0098
D	4.80	5.00	.1890	.1968
Е	3.80	4.00	.1497	.1574
е	1.27 E	BASIC	0.050	BASIC
Н	5.80	6.20	.2284	.2440
h	0.25	0.50	.010	.020
L	0.40	1.27	.016	.050
α	<b>0</b> °	<b>8</b> °	<b>0</b> °	<b>8</b> °

\*For reference only. Controlling dimensions in mm.



#### **Ordering Information**

Part / Order Number	Marking	Shipping Packaging	Package	Temperature
553MLF	553MLF	Tubes	8-pin SOIC	0 to +70° C
553MLFT	553MLF	Tape and Reel	8-pin SOIC	0 to +70° C
553MILF	553MILF	Tubes	8-pin SOIC	-40 to +85 ° C
553MILFT	553MILF	Tape and Reel	8-pin SOIC	-40 to +85 ° C

#### "LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

While the information presented herein has been checked for both accuracy and reliability, Integrated Device Technology (IDT) result from its use. No other circuits, patents, or licenses are implied. This product is intended for use in normal commercial applications. Any other applications such as those requiring extended temperature range, high reliability, or other extraordinary environmental requirements are not recommended without additional processing by IDT. IDT reserves the right to change any circuitry or specifications without notice. IDT does not authorize or warrant any IDT product for use in life support devices or critical medical instruments.

#### Innovate with IDT and accelerate your future networks. Contact:

### www.IDT.com

#### **For Sales**

800-345-7015 408-284-8200 Fax: 408-284-2775

#### For Tech Support

www.idt.com/go/clockhelp

#### **Corporate Headquarters**

Integrated Device Technology, Inc. www.idt.com



© 2012 Integrated Device Technology, Inc. All rights reserved. Product specifications subject to change without notice. IDT and the IDT logo are trademarks of Integrated Device Technology, Inc. Accelerated Thinking is a service mark of Integrated Device Technology, Inc. All other brands, product names and marks are or may be trademarks or registered trademarks used to identify products or services of their respective owners. Printed in USA